

TECHNICAL DATA
DATA SHEET 1057, REV. -**HERMETIC POWER SCHOTTKY RECTIFIER****DESCRIPTION:** A 30 VOLT, 120 AMP, HERMETIC POWER SCHOTTKY RECTIFIER IN A SHD-3/3A/3B PACKAGE.**MAXIMUM RATINGS**ALL RATINGS ARE @ $T_C = 25\text{ }^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED.

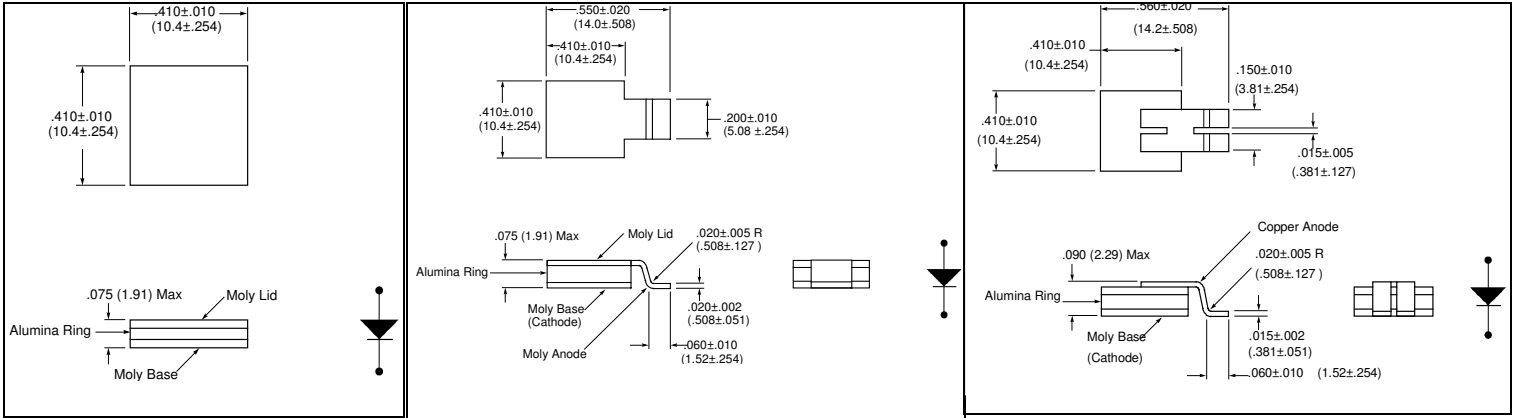
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	30	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_C=100\text{ }^\circ\text{C}$)	I_O	120	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT ($t=10\text{ms}$, Sine)	I_{FSM}	1650	Amps
MAXIMUM JUNCTION CAPACITANCE ($V_r=5\text{V}$)	C_T	6600	pF
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R_{\theta JC}$	0.20	$^\circ\text{C/W}$
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ($I_f = 120\text{ Amps}$) $T_J = 25\text{ }^\circ\text{C}$ $T_J = 125\text{ }^\circ\text{C}$	V_f	0.53 0.43	Volts
MAXIMUM REVERSE CURRENT (I_r @ 30 V PIV) $T_J = 25\text{ }^\circ\text{C}$ $T_J = 125\text{ }^\circ\text{C}$	I_r	12 600	mA

SENSITRON
DATA SHEET 1057, REV. -

MECHANICAL DIMENSIONS: In Inches / mm



SHD-3

SHD-3A

SHD-3B

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